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QUADRUPLE 3-STATE BUFFERS OE LOW

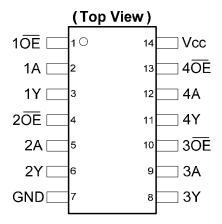
Description

The 74HC125 provides provides four independent buffer gates with 3-state outputs. Each buffer has a separate enable pin that if driven with a high logic level places the corresponding output in the high impedance state. The device is designed for operation with a power supply range of 2.0V to 6.0V.

Features

- Wide Supply Voltage Range from 2.0V to 6.0V
- Sinks or sources 4mA at $V_{CC} = 4.5V$
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs
- ESD Protection Exceeds JESD 22
 - 200-V Machine Model (A115-A)
 - 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



SO-14 / TSSOP-14

Applications

- General Purpose Logic
- Wide array of products such as:
 - PCs, Networking, Notebooks, Netbooks
 - Computer Peripherals, Hard Drives, CD/DVD ROM
 - TV, DVD, DVR, Set Top Box

Notes:

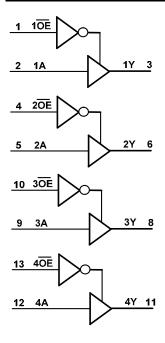
- No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Pin Descriptions

Pin Number	Pin Name	Function	
1	1 0E	Data Enable Input (active low)	
2	1A	Data Input	
3	1Y	Data Output	
4	2 0E	Data Enable Input (active low)	
5	2A	Data Input	
6	2Y	Data Output	
7	GND	Ground	
8	3Y	Data Output	
9	3A	Data Input	
10	3 OE	Data Enable Input (active low)	
11	4Y	Data Outp	
12	4A	Data Input	
13	4OE	Data Enable Input (active low)	
14	Vcc	Supply Voltage	

Logic Diagram



Function Table

Inp	Output	
ŌE	Α	Y
L	Н	Н
L	L	L
Н	Х	Z



Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
Vcc	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range note 3)	-0.5 to +7.0	V
I _{IK}	Input Clamp Current V _I < -0.5V or Vi > V _{CC} +0.5V	±20	mA
lok	Output Clamp Current $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$	±20	mA
Io	Continuous Output Current -0.5V < V _O V _{CC} +0.5V	+/- 25	mA
I _{CC}	Continuous Current Through V _{CC}	50	mA
I _{GND}	Continuous Current Through GND	-50	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
Ртот	Total Power Dissipation	500	mW

Notes:

Recommended Operating Conditions (Note 6) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage		2.0	6.0	V
VI	Input Voltage		0	Vcc	V
Vo	Output Voltage		0	Vcc	V
		$V_{CC} = 2.0V$		625	
Δt/ΔV	Input Transition Rise or Fall Rate	$V_{CC} = 4.5V$		140	ns/V
		V _{CC} = 6.0V		85	
T _A	Operating Free-Air Temperature	_	-40	+125	°C

Note: 6. Unused inputs should be held at V_{CC} or Ground.

^{4.} Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

^{5.} Input Voltage cannot exceed V_{CC} to the extent the Maximum clamp current is exceeded.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Cumbal	Parameter	Test Conditions	V	T _A = -40°0	C to +85°C	T _A = -40°C	to +125°C	Unit
Symbol	Parameter	lest Conditions	Vcc	Min	Max	Min	Max	Unit
			2.0V	1.5		1.5		
V_{IH}	High-level Input Voltage		4.5V	3.15		3.15		V
	Voltage		6.0V	4.2		4.2		
	l avv lavval lamvit		2.0V		0.5		0.5	
V_{IL}	Low-level Input voltage		4.5V		1.35		1.35	V
	vollago		6.0V		1.8		1.8	
		$I_{OH} = -20 \mu A$	2.0V	1.9		1.9		
	High-level Output Voltage	I _{OH} = -20μA	4.5V	4.4		4.4		V
V_{OH}		I _{OH} = -20μA	6.0V	5.9		5.9		
		$I_{OH} = -4.0$ mA	4.5V	3.84		3.7		
		I _{OH} = -5.2mA	6.0V	5.34		5.2		
		I _{OL} = 20μA	2.0V		0.1		0.1	
		I _{OL} = 20μA	4.5V		0.1		0.1	
V_{OL}	Low-level Output Voltage	$I_{OL} = 20\mu A$	6.0V		0.1		0.1	V
	Voltago	I _{OL} = 4mA	4.5V		0.33		0.44	7
		I _{OL} = 5.2mA	6.0V		0.33		0.44	
l _{OZ}	Z State Leakage Current	$V_O = 0 \text{ to } 6.0V$ $V_I = \text{GND or } 6.0V$	6.0V		± 5.0		± 10	μΑ
lį	Input Current	V _I = GND to 5.5V	6.0V		± 1		± 1	μA
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}, I_O = 0$	6.0V		20		40	μΑ

Switching Characteristics

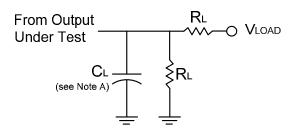
Symbol	Parameter	Test	V		T _A = +25°C		-40°C to +85°C	-40°C to +125°C	Unit
Syllibol	Parameter	Conditions	Vcc	Min	Тур.	Max	Max	Max	Ullit
	D	Figure 1	2.0V	_	30	100	125	150	
t _{PD}	Propagation Delay A _N to Y _N	Figure 1 $C_L = 50 \text{ pF}$	4.5V	_	11	20	25	30	ns
	Delay AN to TN	CL = 30 pr	6.0V	_	9	17	21	26	
		Figure 1	2.0V	_	41	125	155	190	
t _{EN}	t _{EN} Enable Time	Figure 1 $C_L = 50 \text{ pF}$	4.5V	_	15	25	31	38	ns
	OE _N to Y _N	CL = 50 pr	6.0V	_	12	21	26	32	
		Figure 1	2.0V	_	41	125	155	190	
t _{DIS}	<u>Dis</u> able Time	Figure 1 $C_L = 50 \text{ pF}$	4.5V	_	15	25	31	38	ns
	OE to Y _N	CL = 50 pr	6.0V	_	12	21	26	32	
		Figure 1	2.0V	_	14	60	75	90	
t _t Transition time	Figure 1	4.5V	_	5	12	15	18	ns	
		$C_L = 50 pF$	6.0V	_	4	10	13	15	

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

	Parameter	Test Conditions	V _{CC} = 6V	Unit
	i didilictei	rest conditions	Тур	Oilit
$C_{\sf pd}$	Power Dissipation Capacitance per Gate	f = 1MHz	22	pF
Cı	Input Capacitance	$V_I = V_{CC} - \text{ or GND}$	4	pF



Parameter Measurement Information



TEST	Condition
t _{PLZ} (see Notes D and E)	Vload
t _{PZL} (see Notes D and F)	Vload

V	Inputs		V	, ,		В	V Δ
V _{CC}	VI	t_r/t_f	V _M	VLOAD	Մլ	KL	VA
2.0V to 6.0V	V _{CC}	≤3ns	V _{CC} /2	2 X V _{CC}	15,50 pF	2 ΚΩ	10% of V _{CC}

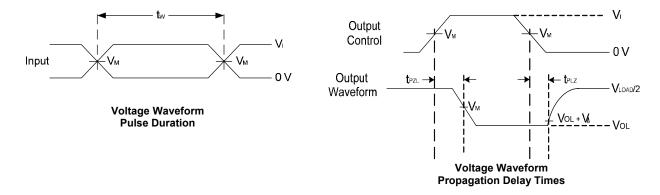


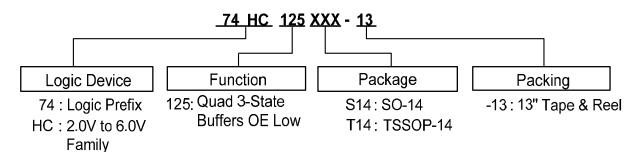
Figure 1 Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 1 MHz.
- C. The inputs are measured one at a time with one transition per measurement.
- D. For the 3 state device t_{PLZ} and t_{PZL} are the same as t_{PD} .
- E. t_{PZL} is measured at V_{M} .
- D. t_{PLZ} is measured at V_{OL} + V_{Δ} .



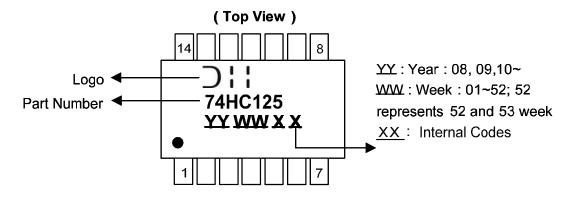
Ordering Information



	Dovice	Davies Backers Code		Device Package Code Packaging		7" Tape and Reel		
	Device	Package Code	Packaging	Quantity	Part Number Suffix			
Pb,	74HC125S14-13	S14	SO-14	2500/Tape & Reel	-13			
Pb,	74HC125T14-13	T14	TSSOP-14	2500/Tape & Reel	-13			

Marking Information

(1) SO-14, TSSOP-14



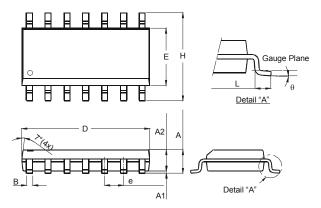
Part Number	Package
74HC125S14	SO-14
74HC125T14	TSSOP-14



Package Outline Dimensions (All dimensions in mm.)

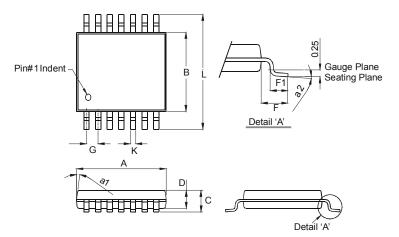
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-14



	SO-14				
Dim	Min	Max			
Α	1.47	1.73			
A 1	0.10	0.25			
A2	1.45	Тур			
В	0.33	0.51			
D	8.53	8.74			
Е	3.80	3.99			
е	1.27	Тур			
Н	5.80	6.20			
L	0.38	1.27			
θ	0°	8°			
All Dimensions in mm					

Package Type: TSSOP-14



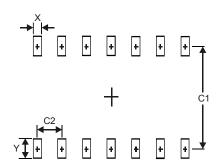
TSSOP-14		
Dim	Min	Max
a1	7° (4X)	
a2	0°	8°
Α	4.9	5.10
В	4.30	4.50
O		1.2
D	8.0	1.05
F	1.00 Typ	
F1	0.45	0.75
G	0.65 Typ	
K	0.19	0.30
L	6.40 Typ	
All Dimensions in mm		



Suggested Pad Layout

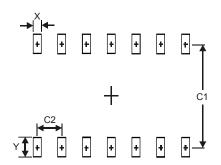
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for latest version.

Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Υ	1.45
C1	5.9
C2	0.65



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